NSN 5961-01-464-8558

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-464-8558

Inclosure Material:

Metal

Overall Length:

1.350 inches

Overall Height:

0.260 inches

Overall Width:

0.545 inches

Mounting Facility Quantity:

1

Internal Configuration:

Field effect

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-254

Mounting Method:

Unthreaded hole

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

200.0 breakdown voltage, drain-to-source, with all other terminals short-circuited to source

Current Rating Per Characteristic:

25.00 amperes drain current

Power Rating Per Characteristic:

125.0 watts total device dissipation

Maximum Operating Tempurature Per Measurement Point:

-55.0 degrees celsius case and 150.0 degrees celsius case

Test Data Document:

09004-38000 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;

excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

3 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

A110a0